

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	10	(memory near cell\$1) AND substrate AND ((bottom lower) near (conduct\$3 electrode\$1)) AND ((first near phase near chang\$3) chalcogenide) AND ((upper top) near (conduct\$3 electrode\$1)) AND pad\$1 AND sidewall\$1 AND ((second near phase near chang\$3) chalcogenide).CLM.	US-PGPUB; USPAT	OR	ON	2005/11/23 08:02
L2	0	(memory near cell\$1) AND substrate AND ((bottom lower) near (conduct\$3 electrode\$1)) AND (first near phase near chang\$3) AND chalcogenide AND ((upper top) near (conduct\$3 electrode\$1)) AND pad\$1 AND sidewall\$1 AND ((second near phase near chang\$3) chalcogenide).CLM.	US-PGPUB; USPAT	OR	ON	2005/11/23 08:02
L3	0	(memory near cell\$1) AND substrate AND ((bottom lower) near (conduct\$3 electrode\$1)) AND (first near phase near chang\$3) AND chalcogenide AND ((upper top) near (conduct\$3 electrode\$1)) AND pad\$1 AND sidewall\$1 AND (second near phase near chang\$3).CLM.	US-PGPUB; USPAT	OR	ON	2005/11/23 08:07
L4	0	(first near phase near chang\$3) with (pad\$1 near2 sidewall\$1) with (second near phase near chang\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:06
L5	0	(first near phase near chang\$3) with sidewall\$1 with (second near phase near chang\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:06
L6	0	(first near phase near chang\$3) same (pad\$1 near2 sidewall\$1) same (second near phase near chang\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:06
L7	0	(first near phase near chang\$3) same (pad\$1 with sidewall\$1) same (second near phase near chang\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:06
L8	0	(first near phase near chang\$3) same sidewall\$1 same (second near phase near chang\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:07

L9	167	(first near phase near chang\$3) with (second near phase near chang\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:11
L10	6	9 and ((first bottom lower) near (conduct\$3 electrode\$1)) with ((second upper top) near (conduct\$3 electrode\$1))	US-PGPUB; USPAT	OR	ON	2005/11/23 08:11
L11	24	9 and electrode\$1	US-PGPUB; USPAT	OR	ON	2005/11/23 08:12
L12	304	(first near phase near chang\$3) and (second near phase near chang\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:11
L13	12	12 and ((first bottom lower) near (conduct\$3 electrode\$1)) with ((second upper top) near (conduct\$3 electrode\$1))	US-PGPUB; USPAT	OR	ON	2005/11/23 08:12
L14	24	9 and electrode\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:12
L15	12	12 and ((first bottom lower) near (conduct\$3 electrode\$1)) with ((second upper top) near (conduct\$3 electrode\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:13
L16	14	12 and ((first bottom lower) near (conduct\$3 electrode\$1)) same ((second upper top) near (conduct\$3 electrode\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:13
L17	19	12 and ((first bottom lower) near (conduct\$3 electrode\$1)) and ((second upper top) near (conduct\$3 electrode\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/11/23 08:13